

# **RV1S9260A**

R08DS0188EJ0100 Rev.1.00

Nov 11,2019

HIGH CMR, 15Mbps CMOS OUTPUT, LOW FORWARD-CURRENT(IF) 3.3V/5V OPERATION, 5-PIN SSOP WITH 8.2mm CREEPAGE DISTANCE (LSSO5) PHOTOCOUPLER

### DESCRIPTION

The RV1S9260A is a photocoupler featuring high-speed switching up to 15Mbps with active low output logic which consists of an AlGaAs LED on the input side and an integrated circuit with a photodiode on the output.

This product enables to low current operation on 3.3V/5V power supply with high noise-tolerant CMR:50kV/us min. and high temperature operation up to Ta=125°C in logic interface circuit.

This package is very small and thin with long creepage distance(8.2mm).

This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

### **FEATURES**

- Small and long creepage (8.2 mm, LSSO5)
- High speed switching (15 Mbps)
- Operating temperature  $(-40 \sim +125^{\circ}C)$
- High common mode transient immunity (CM<sub>H</sub>, CM<sub>L</sub> =  $\pm 50$  kV/ $\mu$ s MIN.)
- High isolation voltage (BV = 5000 Vr.m.s.)
- Low input drive current (IFHL = 2.6mA MAX.)
- Low voltage power supply operation (VDD =  $2.7V \sim 5.5V$ )
- Low pulse width distortion (PWD = 20 ns MAX.)
- Embossed tape product : RV1S9260ACCSP-10Yx#KC0: 3500 pcs/reel
- Pb-Free product
- Safety standard
  - UL : UL1577, Double protection
  - CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
  - VDE : DIN EN 60747-5-5 (Option)

# PIN CONNECTION (Top View) 5 4 3 1. Anode 2. Cathode 3. GND 4. Vo 5. Vod

### TRUTH TABLE

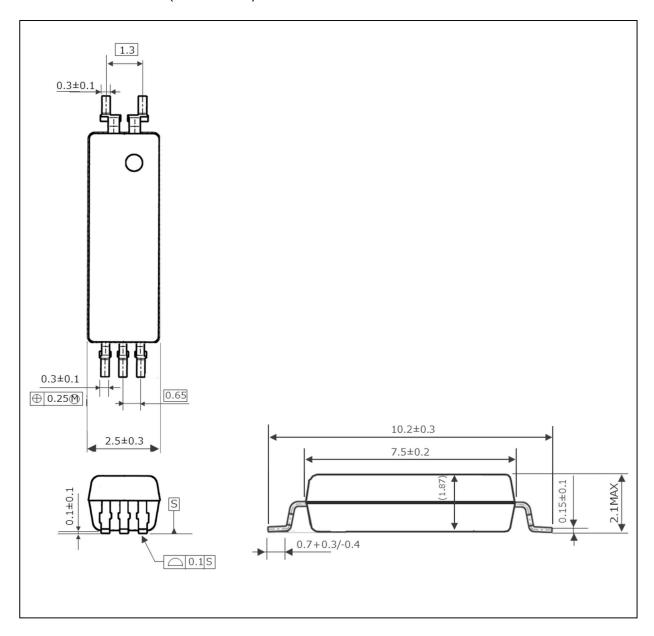
| LED | OUTPUT |
|-----|--------|
| ON  | L      |
| OFF | Н      |

### **APPLICATIONS**

- Robot controller
- Industrial inverter
- AC Servo
- FA Network
- Measurement equipment

Start of mass production Nov.2019

# PACKAGE DIMENSIONS (UNIT: mm)

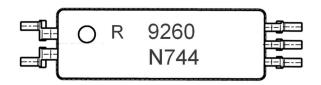


Weight: 0.075g (Typ.)

# PHOTOCOUPLER CONSTRUCTION

| Parameter          | MIN.    |
|--------------------|---------|
| Air Distance       | 8.2 mm  |
| Creepage Distance  | 8.2 mm  |
| Isolation Distance | 0.15 mm |

# MARKING EXAMPLE



| F    | ર   | An initial of "Renesas" |                                 |  |
|------|-----|-------------------------|---------------------------------|--|
| 92   | 60  | Product Part Number *   |                                 |  |
|      | )   | No.1 pin Mark           |                                 |  |
| N744 | N   | Rank Code               |                                 |  |
|      | 744 | Assembly Lot            |                                 |  |
|      |     | 7                       | Last one-digit of Assembly Year |  |
|      |     | 44 Weekly Serial Code   |                                 |  |

\*) Applicable type numbers listed below

RV1S 9260 ACCSP-10Yx

Marking type number. " RV1S" and "ACCSP-10Yx" " are omitted from original type number

# ORDERING INFORMATION

| Part Number            | Order Number               | Solder Plating<br>Specification | Packing Style               | Safety Standard<br>Approval  | Application<br>Part<br>Number*1 |
|------------------------|----------------------------|---------------------------------|-----------------------------|------------------------------|---------------------------------|
| RV1S9260ACCSP<br>-10YC | RV1S9260ACCSP<br>-10YC#SC0 | Pb-Free and<br>Halogen Free     | 20 pcs(Tape 20 pcs cut)     | Standard products (UL, CSA   | RV1S9260A                       |
|                        | RV1S9260ACCSP<br>-10YC#KC0 | (Ni/Pd/Au)                      | Embossed Tape 3500 pcs/reel | approved)                    |                                 |
| RV1S9260ACCSP          | RV1S9260ACCSP<br>-10YV#SC0 |                                 | 20 pcs(Tape 20 pcs cut)     | UL, CSA,<br>DIN EN 60747-5-5 |                                 |
| -10YV                  | RV1S9260ACCSP<br>-10YV#KC0 |                                 | Embossed Tape 3500 pcs/reel | approved                     |                                 |

Notes:\*1. For the application of the Safety Standard, following part number should be used.

# ABSOLUTELY MAXIMUM RATINGS (T<sub>A</sub> =25°C, unless otherwise specified)

|                               | Parameter                  | Symbol              | Ratings                     | Unit    |
|-------------------------------|----------------------------|---------------------|-----------------------------|---------|
| Diode                         | Forward Current            | lF                  | 20                          | mA      |
|                               | Reverse Voltage            | V <sub>R</sub>      | 5                           | V       |
|                               | Power Dissipation Derating | ΔP <sub>D</sub> /°C | 1.2 (T <sub>A</sub> ≧110°C) | mW/°C   |
|                               | Power Dissipation          | PD                  | 45                          | mW      |
| Detector                      | Supply Voltage             | V <sub>DD</sub>     | 6                           | V       |
|                               | Output Voltage             | Vo                  | 6                           | V       |
|                               | Output Current             | lo                  | 10                          | mA      |
|                               | Power Dissipation Derating | ΔPc/°C              | 4.15 (T <sub>A</sub> ≧85°C) | mW/°C   |
|                               | Power Dissipation          | Pc                  | 250                         | mW      |
| Isolation Voltage *1          |                            | BV                  | 5000                        | Vr.m.s. |
| Operating Ambient Temperature |                            | TA                  | -40 <b>~</b> +125           | °C      |
| Storage Temperature           |                            | T <sub>stg</sub>    | -55 <b>~</b> +150           | °C      |

Notes: 1. AC Voltage for 1minite at  $T_A$ =25°C, RH=60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

# RECOMMENDED OPERATING CONDITIONS

| Parameter                  | Symbol          | MIN. | TYP. | MAX | Unit |
|----------------------------|-----------------|------|------|-----|------|
| Low Level forward voltage  | V <sub>FL</sub> | 0    |      | 8.0 | V    |
| High Level Forward Current | I <sub>FH</sub> | 3    |      | 6   | mA   |
| Supply Voltage             | $V_{DD}$        | 2.7  |      | 5.5 | V    |

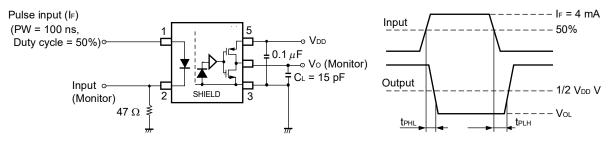
# **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub>= -40 to +125°C,  $V_{DD}$  = 2.7 to 5.5 V, unless otherwise specified)

|          | Parameter                 | Symbol           | Conditions   | MIN.                 | TYP.*1   | MAX. | Unit  |
|----------|---------------------------|------------------|--|----------------------|----------|------|-------|
| Diode    | Forward Voltage           | VF               | I <sub>F</sub> = 6 mA, T <sub>A</sub> = 25°C                 | 1.4                  | 1.55     | 1.7  | V     |
|          | Reverse Current           | I <sub>R</sub>   | V <sub>R</sub> = 3 V, T <sub>A</sub> = 25°C                  |                      |          | 10   | μA    |
|          | Terminal Capacitance      | Ct               | V <sub>F</sub> = 0 V, f = 1 MHz, T <sub>A</sub> = 25°C       |                      | 30       |      | pF    |
| Detector | High Level Output Current | I <sub>DDH</sub> | I <sub>F</sub> = 0 mA  |                      | 1.1      | 2    | mA    |
|          | Low Level Output Current  | I <sub>DDL</sub> | I <sub>F</sub> = 3 mA  |                      | 1.0      | 2    |       |
|          | High Level Output Voltage | V <sub>OH</sub>  | $I_0 = -3.2 \text{mA}, I_F = 0 \text{ mA}$                   | V <sub>DD</sub> -1.0 | $V_{DD}$ |      | V     |
|          |                           |                  | $I_0 = -20 \mu A, I_F = 0 \text{ mA}$                        | V <sub>DD</sub> -0.1 | $V_{DD}$ |      |       |
|          | Low Level Output Voltage  | V <sub>OL</sub>  | $I_0 = 3.2 \text{mA}, I_F = 3 \text{ mA}$                    |                      | 0.13     | 0.4  | 1     |
|          |                           |                  | $I_0 = 20 \mu\text{A}, I_F = 3 \text{mA}$                    |                      | 0.001    | 0.1  |       |
| Coupled  | Threshold Input Voltage   | I <sub>FHL</sub> | V <sub>O</sub> < 0.4 V                                       |                      | 0.9      | 2.6  | mA    |
|          | (H to L)                  |                  |  |                      |          |      |       |
|          | Propagation Delay Time    | t <sub>PHL</sub> | I <sub>F</sub> = 4 mA ⇔ 0mA                                  |                      | 38       | 60   | ns    |
|          | (H to L)*2                |                  | V <sub>DD</sub> = 3.3V,5 V                                   |                      |          |      |       |
|          | Propagation Delay Time    | t <sub>PLH</sub> | C <sub>L</sub> = 15 pF                                       |                      | 36       | 60   |       |
|          | (L to H)*2                |                  |  |                      |          |      |       |
|          | Pulse Width Distortion*2  | PWD              |  |                      | 2        | 20   |       |
|          | Propagation Delay Skew    | t <sub>PSK</sub> |  |                      |          | 25   |       |
|          | Rise Time                 | t <sub>r</sub>   |  |                      | 5        |      |       |
|          | Fall Time                 | t <sub>f</sub>   |  |                      | 5        |      |       |
|          | Common Mode               | СМн              | $I_F = 0 \text{ mA}, V_O > 4 \text{ V(V}_{DD} = 5\text{V}),$ | 50                   | 60       |      | kV/μs |
|          | Transient Immunity at     |                  | $V_0 > 2.3 \text{ V(V}_{DD} = 3.3 \text{V)},$                |                      |          |      |       |
|          | High Level Output*3       |                  | V <sub>CM</sub> =1.5kV, T <sub>A</sub> = 25°C                |                      |          |      |       |
|          | Common Mode               | CML              | I <sub>F</sub> = 3 mA,                                       | 50                   | 60       |      |       |
|          | Transient Immunity at     |                  | $V_0 < 0.4 \ V(V_{DD} = 3.3 V, 5 V),$                        |                      |          |      |       |
|          | Low Level Output*3        |                  | V <sub>CM</sub> =1.5kV, T <sub>A</sub> = 25°C                |                      |          |      |       |

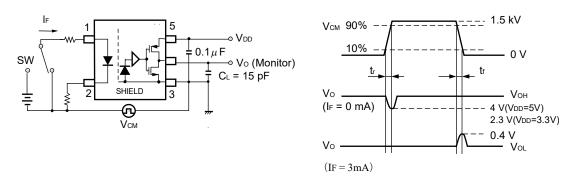
Note2: 1. Typical values at T<sub>A</sub> = 25°C

2. Test circuit for propagation delay time measurement



**Remark** C<sub>L</sub> includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity measurement

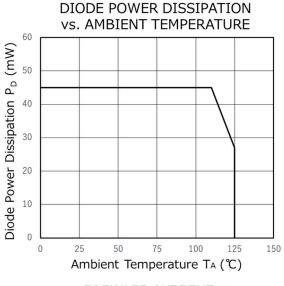


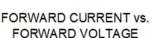
 $\textbf{Remark} \qquad C_L \text{ includes probe and stray wiring capacitance}.$ 

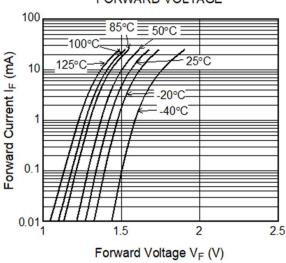
### **USAGE CAUTIONS**

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1  $\mu$ F is used between  $V_{DD}$  and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

# TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)







HIGH LEVEL OUTPUT VOLTAGE vs.

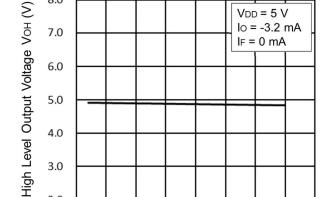
AMBIENT TEMPERATURE

 $V_{DD} = 5 V$ 

lo = -3.2 mA

100 125

150



25

50

Ambient Temperature TA (°C)

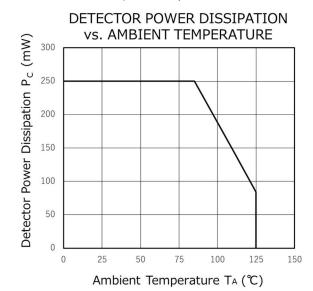
75

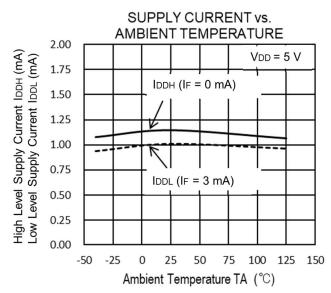
8.0

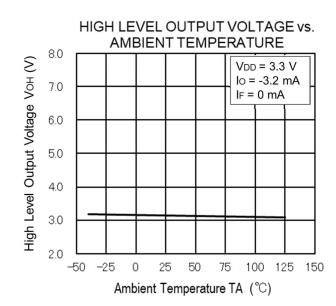
2.0

-50

-25



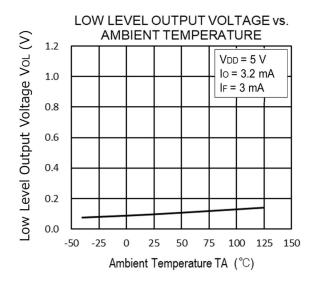


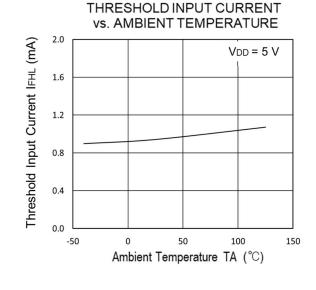


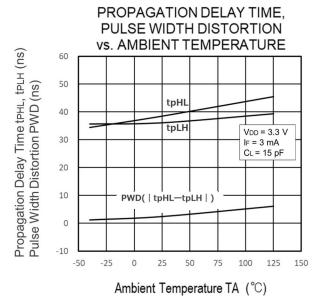
Remark The graphs indicate nominal characteristics

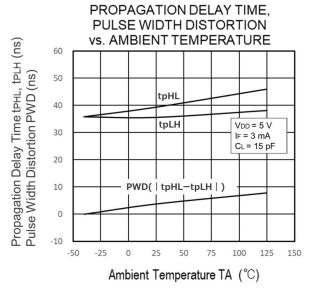
R08DS0188EJ0100 Rev.1.00 Page 7 of 14 Nov 11,2019 RENESAS

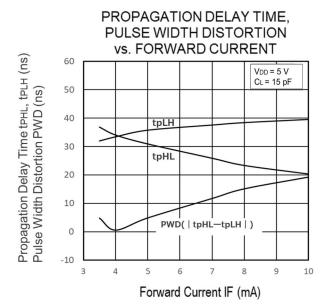
# TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)





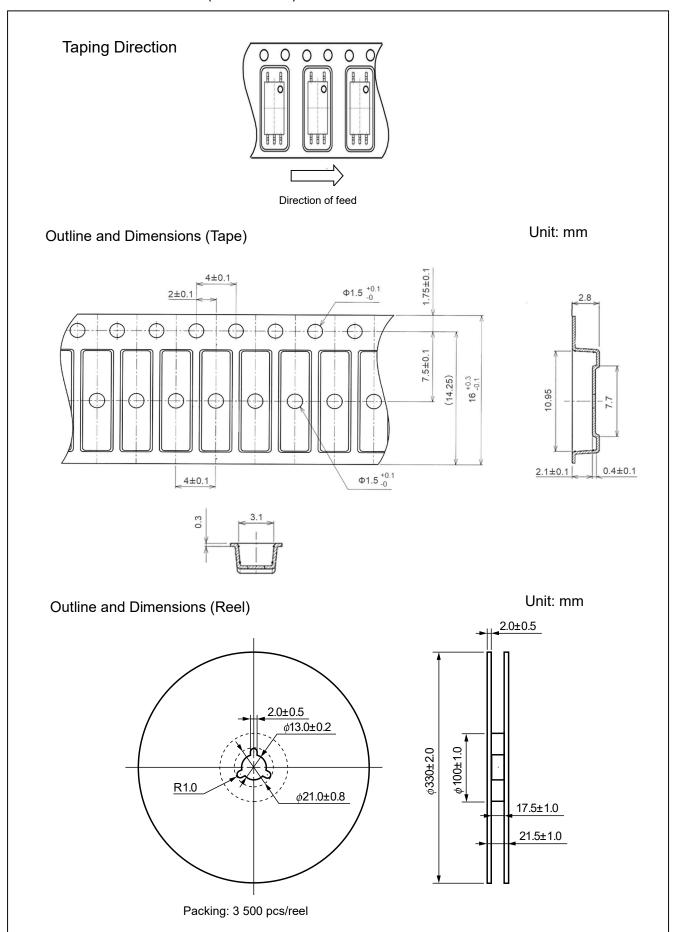




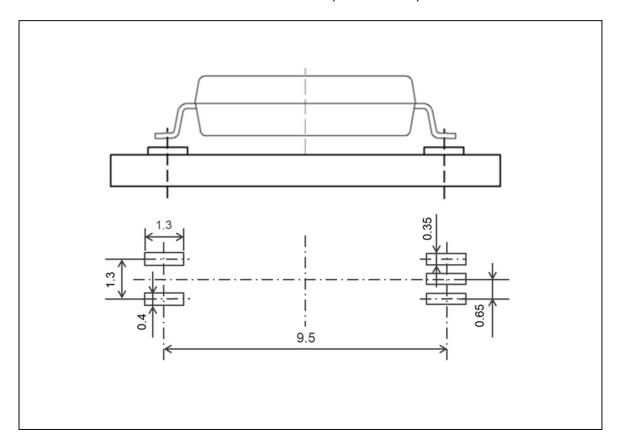


**Remark** The graphs indicate nominal characteristics.

# TAPING SPECIFICATIONS (UNIT: mm)



# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

### NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering

Peak reflow temperature 260°C or below (package surface temperature)

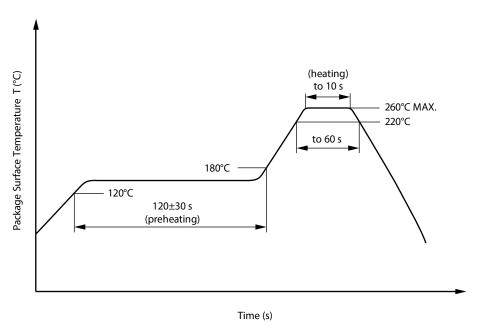
Time of peak reflow temperature
 Time of temperature higher than 220°C
 Time to probably temperature from 130 to 180°C

Time to preheat temperature from 120 to 180°C 120±30 s

• Number of reflows Three

Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



# (2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times
 Flux
 One (Allowed to be dipped in solder including plastic mold portion.)
 Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

### (3) Soldering by Soldering Iron

Peak Temperature (lead part temperature)
 Time (each pins)
 350°C or below
 3 seconds or less

Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

### (4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.

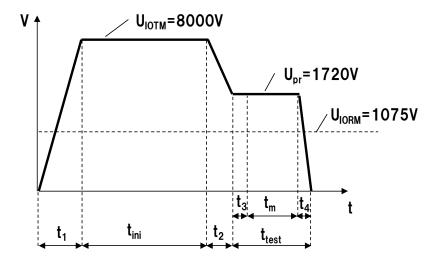
### 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

# SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter  | Symbol            | Rating            | Unit              |
|--|-------------------|-------------------|-------------------|
| Climatic test class (IEC 60068-1/DIN EN 60068-1)                           |                   | 40/125/21         |                   |
| Dielectric strength  |                   |                   |                   |
| maximum operating isolation voltage  | UIORM             | 1 075             | $V_{\text{peak}}$ |
| Test voltage (partial discharge test, procedure a for type test and random | $U_pr$            | 1 720             | $V_{peak}$        |
| test)  |                   |                   |                   |
| $U_{pr} = 1.6 \times U_{IORM.}$ , $P_d < 5 pC$                             |                   |                   |                   |
| Test voltage (partial discharge test, procedure b for all devices)         | $U_pr$            | 2 016             | $V_{peak}$        |
| $U_{pr} = 1.875 \times U_{IORM.}, P_d < 5 pC$                              | Opr               | 2010              | <b>∨</b> peak     |
| Highest permissible overvoltage  | U <sub>ІОТМ</sub> | 8 000             | $V_{\text{peak}}$ |
| Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))              |                   | 2                 |                   |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))          | CTI               | 400               |                   |
| Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))                   |                   | П                 |                   |
| Storage temperature range  | T <sub>stg</sub>  | -55 <b>~</b> +150 | °C                |
| Operating temperature range  | T <sub>A</sub>    | -40~+125          | °C                |
| Isolation resistance, minimum value  |                   |                   |                   |
| V <sub>IO</sub> = 500 V dc at T <sub>A</sub> = 25°C                        | Ris MIN.          | 10 <sup>12</sup>  | Ω                 |
| V <sub>IO</sub> = 500 V dc at T <sub>A</sub> MAX. at least 100°C           | Ris MIN.          | 10 <sup>11</sup>  | Ω                 |
| Safety maximum ratings (maximum permissible in case of fault, see thermal  |                   |                   |                   |
| derating curve)  |                   |                   |                   |
| Package temperature  | Tsi               | 175               | °C                |
| Current (input current I <sub>F</sub> , Psi = 0)                           | Isi               | 400               | mA                |
| Power (output or total power dissipation)                                  | Psi               | 700               | mW                |
| Isolation resistanceV <sub>IO</sub> = 500 V dc at T <sub>A</sub> = Tsi     | Ris MIN.          | 10 <sup>9</sup>   | Ω                 |

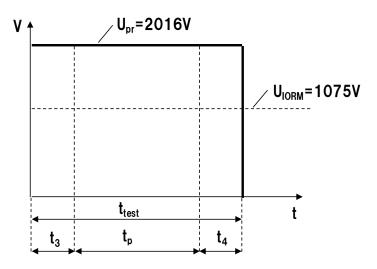
# Method a) Destructive Test, Type and Sample Test



 $t_1,t_2$ =1 to 10 sec  $t_3,t_4$ =1 sec  $t_m \, (\text{PARTIAL DISCHARGE}) = 10$  sec  $t_{\text{test}}$ =12 sec

t<sub>ini</sub>=60 sec

# Method b) Non-destructive Test, 100% Production Test



$$t_3,t_4$$
=0.1 sec  
 $t_p$  (PARTIAL DISCHARGE) = 1.0 sec  
 $t_{test}$ =1.2 sec

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
  - Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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(Rev.4.0-1 November 2017)



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